VS-HFA16PB120HN3

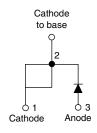
Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 16 A



www.vishay.com

TO-247AC modified



PRIMARY CHARACTERISTICS						
I _{F(AV)}	16 A					
V _R	1200 V					
V _F at I _F	2.3 V					
t _{rr} typ.	30 ns					
T _J max.	150 °C					
Package	TO-247AC modified (2 pins)					
Circuit configuration	Single					

FEATURES

- Ultrafast and ultrasoft recovery
- \bullet Very low I_{RRM} and Q_{rr}
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA16PB120HN3 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 16 A continuous current. the VS-HFA16PB120HN3 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{BBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA16PB120HN3 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V _R		1200	V		
Maximum continuous forward current	I _F	T _C = 100 °C	16			
Single pulse forward current	I _{FSM}		190	А		
Maximum repetitive forward current	I _{FRM}		64			
Maximum power discipation	P _D	T _C = 25 °C	151	W		
Maximum power dissipation		T _C = 100 °C	60	vv		
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C		

Revision: 25-Sep-2019

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Document Number: 94717

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SHAY

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		1200	-	-	
		I _F = 16 A		-	2.5	3.0	v
Maximum forward voltage	V_{FM}	I _F = 32 A	See fig. 1	-	3.2	3.93	
		I _F = 16 A, T _J = 125 °C		-	2.3	2.7	
Maximum reverse leakage		$V_{R} = V_{R}$ rated		-	0.75	20	
current	IRM	T_J = 125 °C, V_R = 0.8 x V_R rated	See fig. 2	-	375	2000	μA
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	27	40	pF
Series inductance	L _S	Measured lead to lead 5 mm from p	ackage body	-	8.0	-	nH

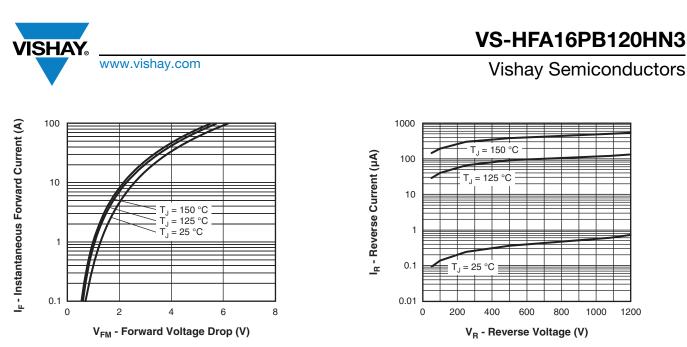
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	A/μs, V _R = 30 V	-	30	-	
Reverse recovery time See fig. 5, 10	t _{rr1}	$T_J = 25 \ ^{\circ}C$		-	90	-	ns
,	t _{rr2}	T _J = 125 °C		-	164	-	
Peak recovery current See fig. 6	I _{RRM1}	$T_J = 25 \ ^{\circ}C$	I _F = 16 A	-	5.8	-	А
	I _{RRM2}	T _J = 125 °C		-	8.3	-	~
Reverse recovery charge	Q _{rr1}	$T_J = 25 \ ^{\circ}C$	dl _F /dt = 200 A/µs V _B = 200 V	-	260	-	nC
See fig. 7	Q _{rr2}	T _J = 125 °C		-	680	-	ne
Peak rate of fall of recovery current during t _b	dl _{(rec)M} /dt1	T _J = 25 °C		-	120	-	A∕µs
See fig. 8	dl _{(rec)M} /dt2	T _J = 125 °C		-	76	-	λγμs

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	0.83		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.50	-		
Weight			-	2.0	-	g	
weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC modified (JEDEC [®])		HFA16	PB120H		

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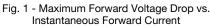


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

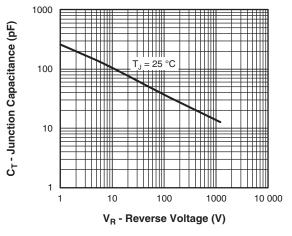
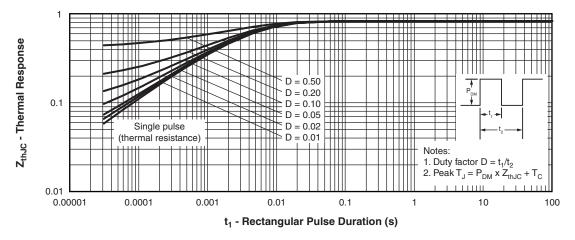


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

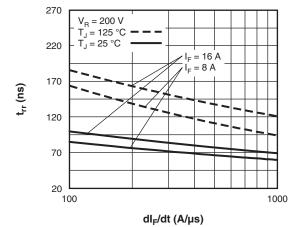




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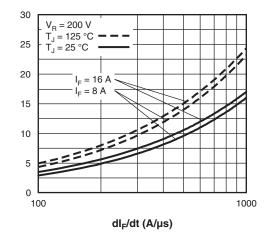


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

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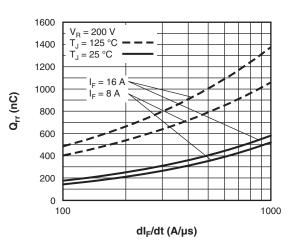


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

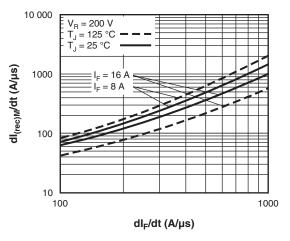


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt (Per Leg)

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I_{RR} (A)



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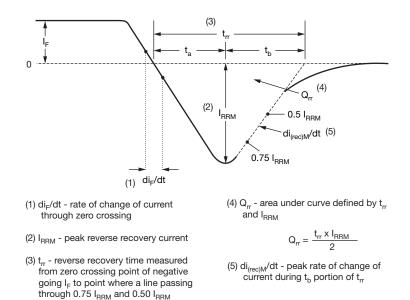


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

SHAY

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Device code VS- HF A 16 PB	120	н	N3
	6	7	8
 Vishay Semiconductors prod HEXFRED[®] family Electron irradiated Current rating (16 = 16 A) PB = TO-247AC modified Voltage rating: (120 = 1200 V) H = AEC-Q101 qualified Environmental digit: 			

extrapolated to zero current.

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-HFA16PB120HN3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95253				
Part marking information	www.vishay.com/doc?95442				
SPICE model	www.vishay.com/doc?95672				

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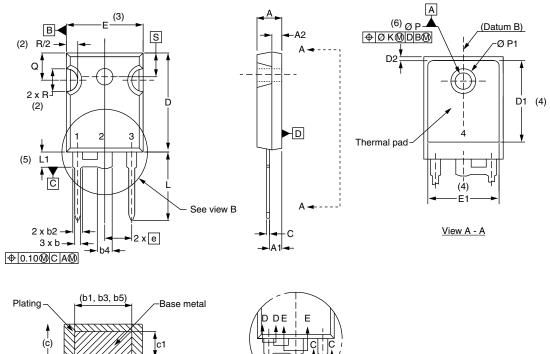
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TO-247AC modified

DIMENSIONS in millimeters and inches



Section C - C, D - D, E - E

(4)

(b. b2. b4)

DDE	E	$ \rangle$
		J/

/iew	'B

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NUTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	INCHES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.530	-	
е	5.46 BSC		0.215 BSC		
ØК	0.254		0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217 BSC		

Notes

- ⁽¹⁾ Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension c

Revision: 11-Dec-2019

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